

IPP60R125C6

Request a Quote

IPP60R125C6 Information

	Part Number	IPP60R125C6
	Manufacturer	Infineon Technologies
www.heiseper.com	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
	Description	MOSFET N-CH 600V 30A TO220
11	Package	TO-220-3
		For the pricing/inventory/lead time, please contact us
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPP60R125C6 Specifications

Manufacturer Part Number	IPP60R125C6
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	30A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.5V @ 960µA
Gate Charge (Qg) (Max) @ Vgs	96nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2127pF @ 100V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	219W (Tc)
Rds On (Max) @ Id, Vgs	125 mOhm @ 14.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO-220-3
Package / Case	TO-220-3
	Report errors?

IPP60R125C6 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE SUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPP60R125C6 Payment Methods



IPP60R125C6 Shipping Methods



If you have any question about IPP60R125C6, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com